

## AMENDMENTS

### In the Specification

Please amends paragraphs as follows:

[0005] Since the maintenance period for the CS signal is typically 1T ~~cycleperiod period~~, the command signal is issued 2T cycles before the submission of the CS signal by convention. Because 2T cycles is a relatively long period, the memory unit can still read the command signal at a time frame identical to the CS signal when the memory unit is triggered by the CS signal, even if the signal transmission distance is long.

### Summary of Invention

[0007] Accordingly, one object of the present invention is to provide a memory address driver capable of providing a 1T or a 2T ~~cycleperiod period~~ timing command signal to the memory unit depending on actual operating conditions. Aside from increasing the capacity of a computer system to access memory data, the design also improves system stability.

[0008] To achieve these and other advantages and in accordance with the purpose of the invention, as embodied and broadly described herein, the invention provides a programmable memory controller. The memory controller includes a main memory controller, a command decoder, a ~~cycleperiod period~~ setting device, a command-sequencing device and a command signal output device. When the programmable memory controller needs to access data within a memory unit, the main memory controller issues a request signal. The command decoder receives the request signal, decodes the request signal and outputs a plurality of command signals. The command-sequencing device receives the command signals and orders the command signals according to a ~~cycleperiod period~~ setting signal submitted from the ~~cycleperiod period~~ setting device. The command signal output device receives the ordered command signals in sequence and controls the maintenance period of various ordered command signal cycles in the process of transferring to the memory according to the ~~cycleperiod period~~ setting signal provided by the ~~cycleperiod period~~ setting device.

[0009] The memory access structure inside the programmable memory controller according to this invention utilizes a plurality of command signals to control memory data access. The

memory access structure includes a control chipset and a memory slot. The control chipset further includes a built-in programmable memory controller. When the control chipset needs to access data inside the memory, the built-in programmable memory controller inside the control chipset outputs the maintenance period for each command signal ~~cycleperiod period~~. The memory slot receives the command signal for outputting to the memory.

[0010] In one preferred embodiment of this invention, the maintenance period for each command signal ~~cycleperiod period~~ may depend on the traveling distance of the command signal. The traveling distance of each command signal, in turn, depends on the length of trace line from the control chipset to a particular pin inside the memory slot.

[0011] Hence, according to the transmission distance of a command signal, a system having two different ~~cycleperiod period~~ maintenance periods, for example, a first ~~cycleperiod period~~ period (1T) and a second ~~cycleperiod period~~ period (2T), may be established. In general, a preset distance of travel is often used as a criteria for assigning command signals to the first ~~cycleperiod period~~ period or the second ~~cycleperiod period~~ period. If travel distance of a command signal is smaller than the preset distance, the command signal is maintained for a first ~~cycleperiod period~~ period. On the other hand, if travel distance of a command signal is greater than the preset distance, the command signal is maintained for a second ~~cycleperiod period~~ period. In general, the preset distance is a measure of the length of a trace line from a memory slot pin to the control chipset.

[0020] Fig. 1 is a timing diagram showing the signals received by a memory controller according to a preferred embodiment of this invention. When the memory unit receives the CS signal, the CMD signal is read at an identical time frame during the falling edge of the CS signal, that is, at the time period between a and b. Since the travel distance of the CMD signal from the memory controller to each memory unit is different from the CS signal, the CMD signal may drift to the right under an identical time frame (the dash line section). For a memory unit located far away from the memory controller, a CMD signal having a larger ~~cycleperiod period~~ maintenance period (for example, two clocking cycles or 2T cycles) must be submitted from the memory controller before the CS signal. The CMD signal arrives at the memory unit so that the CMD signal can be read just before the arrival of the triggering CS signal. For a memory unit located close to the memory controller, a CMD signal having a smaller ~~cycleperiod period~~ maintenance period (for example, one clocking ~~cycleperiod period~~ or 1T ~~cycleperiod period~~) and the CS signal may be submitted at about the same time from the memory controller. The CMD signal arrives just before the CS signal triggers the memory unit.

[0021] This invention provides different ~~cycleperiod period~~ maintenance period (1T or 2T) for the CMD signal according to the distance between the control chipset and each memory units so that memory access may attain an optimum efficiency.

[0022] Fig. 2 is a block diagram showing the circuit layout of a programmable memory controller according to one preferred embodiment of this invention. The programmable memory control chip comprises a main memory controller 210, a command decoder 220, a command-sequencing device 230, a command signal output device 250 and a ~~cycleperiod period~~ setting device 240. When the main memory controller 210 needs to use the memory units 260 plugged into the memory slot, a request signal is sent to the command decoder 220. The command decoder 220 receives the request signal and decodes the request signal to produce a plurality of command signals. The command signals are transferred to the command-sequencing device 230. The command-sequencing device 230 receives the command signals and ~~cycleperiod period~~ setting signals from the ~~cycleperiod period~~ setting device 240. According to the ~~cycleperiod period~~ setting signal (setting the ~~cycleperiod period~~ maintenance period for the command signals, that is, signals are maintained according to the set period), the command signals are sequenced and output. When the ordered command signals are sequentially input to the command signal output device 250, the command signal output device 250 also receives the ~~cycleperiod period~~ setting control signal from the ~~cycleperiod period~~ setting device 240 at the same time. Thereafter, the ~~cycleperiod period~~ maintenance period of the ordered command signal submitted from the command-sequencing device 230 is adjusted to the ~~cycleperiod period~~ maintenance period of the command signals of this ~~cycleperiod period~~ setting signal. Note that the ~~cycleperiod period~~ setting signal sets the ~~cycleperiod period~~ maintenance period of the command signal. In general, the ~~cycleperiod period~~ maintenance period can be a 1T ~~cycleperiod period~~ or a 2T ~~cycleperiod period~~. Finally, the command output device 250 transmits the sequenced and ~~cycleperiod period~~ maintenance period adjusted command signals to the memory unit for controlled reading of data.

[0023] The aforementioned control signals may be written down as a program code and stored inside a basic input/output system (BIOS). The program codes may include the maintenance periods required to transmit command signals to various memory units (can be 1T ~~cycleperiod period~~ or 2T cycles). When a request signal is issued, related program code may be retrieved from the BIOS according to the trace length from the memory slot to the control chipset and fed to the ~~cycleperiod period~~ setting device 240 via the control signal for decoding. Thus, the maintenance period for a particular command signal ~~cycleperiod period~~ can be controlled. Furthermore, existing circuits inside a DRAM controller may be used to form the command decoder 220, the command-sequencing device 230, the ~~cycleperiod period~~ setting device 240 and the command signal output device 250. Some variation to fit a particular requirement, or some other means of constructing the circuits, are also permitted.

[0024] According to the actual connection between the control chipset and the memory slot on a motherboard, a conventional motherboard having four memory slots thereon is chosen as an example in the following description. Figs. 3A and 3B are block diagrams showing the circuit

layout of a memory access structure that incorporates a programmable memory controller according to a first and a second embodiment of this invention. In Fig. 3A, the control chipset 310 has two memory controllers 305 and 307. The memory controller 305 connects with two memory slots 320 and 330 nearest to the control chipset 310. The other memory controller 307 connects with another two memory slots 340 and 350 farthest from the control chipset 310. A ~~cycleperiod~~ period maintenance period of 1T ~~cycleperiod~~ period is used for sending the command signal from the memory controller 305 to the memory slots 320 and 330. On the other hand, a ~~cycleperiod~~ period maintenance period of 2T cycles is used for sending the command signal from the memory controller 305 to the memory slots 340 and 350. In a slightly different connectivity method shown in Fig. 3B, the control chipset 360 also has two memory controllers 355 and 357. However, the memory controller 355 connects with a memory slot 370 nearest the control chipset 360 only. The other memory controller 357 connects with three memory slots 380, 390 and 395 that are further away from the control chipset 360. Similarly, a ~~cycleperiod~~ period maintenance period of 1T ~~cycleperiod~~ period is used for sending the command signal from the memory controller 357 to the memory slot 370. Meanwhile, a ~~cycleperiod~~ period maintenance period of 2T cycles is used for sending the command signal from the memory controller 357 to the memory slots 380, 390 and 395. In practice, the number of memory slots on a motherboard using either 1T or 2T cycles may be determined according to the actual requirements. In general, if the trace length from a memory slot pin to a control chipset (310 or 360) is smaller than 2500mils, command signals may be transmitted using 1T ~~cycleperiod~~ period. If the trace length is greater than 2500mils, 2T cycles is often preferred.

[0025] In addition, a command signal using 1T ~~cycleperiod~~ period maintenance period requires less time to access multiple batches of data from memory than a command signal using 2T ~~cycleperiod~~ period maintenance period. Consequently, command signals using 1T ~~cycleperiod~~ period maintenance period are more suitable for high clocking rate memory while command signals using 2T ~~cycleperiod~~ period maintenance period are more suitable for low clocking rate memory. Thus, if high clocking rate memory such as double data rate synchronous dynamic random access memory (DDR SDRAM) is plugged into a memory slot that uses 1T ~~cycleperiod~~ period command signals, much better results will be obtained with this invention than plugging synchronous dynamic random access memory (SDRAM). Hence, in Figs. 3A and 3B, the memory slots 320, 330 and 370 can be designed to support DDR SDRAM while the memory slots 340, 350, 380, 390 and 395 can be designed to support SDRAM. In general, to accommodate existing motherboards, both the DDR SDRAM and the SDRAM, will coexist together.

[0026] In summary, this invention provides a programmable memory control chip that can set the ~~cycleperiod~~ period maintenance period (1T/2T) of command signals through a ~~cycleperiod~~ period setting device. In addition, the connection between a control chipset on a motherboard

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and particular memory slot position can be selected. Ultimately, memory-accessing capability of the computer system is optimized.